

Adaptive 100/120 Hz Current Ripple Remover Max Input Current ≤ 60 mA

Features

- Regulator for adaptive 100/120 Hz current ripple remove
- Built-in zener diode for input voltage clamping
- Built-in 100 V power MOSFET
- Programmable amplitude LED current ripple
- Programmable maximum cathode voltage of LED
- Programmable maximum LED current
- Optimized for TRIAC dimming, 1% brightness without flicker
- The current ripple is less than ±1%
- SOT23-3, SOT89-3 packages

Descriptions

DIO8242E is a regulator for driving internal NMOSFET to remove the 100/120 Hz LED string current ripple on AC/DC power.

Patented control strategies are optimized for remover current ripple. Novel circuit design makes a lower BOM and high cost-effective for flickerless filament.

Applications

LED lighting

Ordering Information

Ordering Part No.	Top Marking	MSL	RoHS	T _A	Package	
DIO8242EST3	1016	3	Green	-40 to 125°C	SOT23-3	Tape & Reel,3000
DIO8242ETC3	1016	3	Green	-40 to 125°C	SOT89-3	Tape & Reel,2500



Pin Assignment

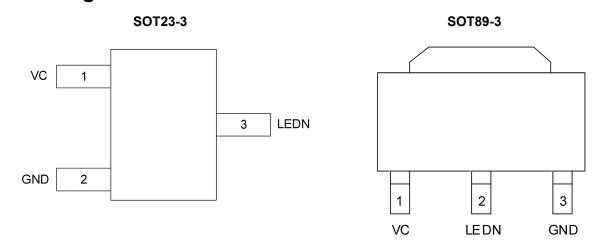


Figure 1. Top view

Pin Descriptions

Pin Name	Description
GND	Power ground
VC	LED current ripple programming
LEDN	Connect to the cathode of LED string



Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maxim rating conditions for extended periods may affect device reliability.

Symbol	Parameter	Rating	Unit	
V _{LEDN}	LEDN	100	V	
V _{VC}	VC	vc		
TJ	Junction temperature	Junction temperature		
TL	Lead temperature	260	°C	
T _{STG}	Storage temperature	-65 to 150	°C	
В	Thermal resistance	SOT23-3	220	°C/W
$R_{ hetaJA}$		SOT89-3	80	
Rejc	Thermal resistance	SOT23-3	130	°C/W
	Thermal resistance	SOT89-3	25	C/VV

Recommend Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Rating	Unit
V _{LEDN}	LEDN		< 100	V
TJ	Junction temperature		125	°C
	Under point V _{LEDN}		0.8~1.2	V
	Power consumption SOT23-3 SOT89-3		< 300	10/
			< 650	mW



Electrical Characteristics

Typical value: Vcc = 3.6 V, T_A = 25°C, unless otherwise specified.

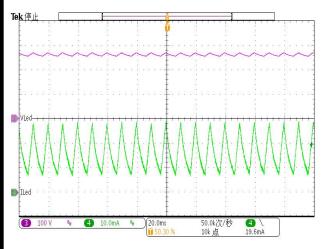
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{ST}	Start-up current				1	uA
V_{REF}	LEDN compare voltage			9		V
Ісьмт	LED current limit				60	mA
R _{DS(ON)}	MOS R _{DS(ON)}			16		Ω
BV	Breakdown voltage		100			V

Note:

(1) Specifications subject to change without notice.

Typical Performance Characteristics

 C_{VC} = 1 μ F, C_{EC} = 8.2 μ F, unless otherwise specified.



 $(V_{AC} = 220 \text{ V}, V_{LED} = 250 \text{ V}, I_{LED} = 15 \text{ mA})$ Figure 2. LED current ripple without DIO8242E

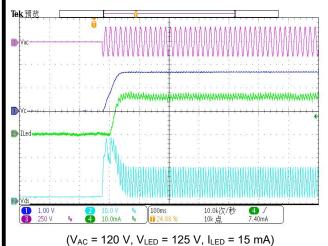
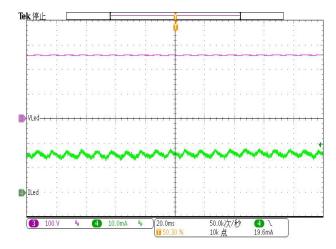
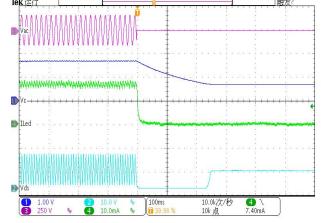


Figure 4. AC source power ON



 $(V_{AC} = 220 \text{ V}, V_{LED} = 250 \text{ V}, I_{LED} = 15 \text{ mA})$

Figure 3. LED current ripple with DIO8242E

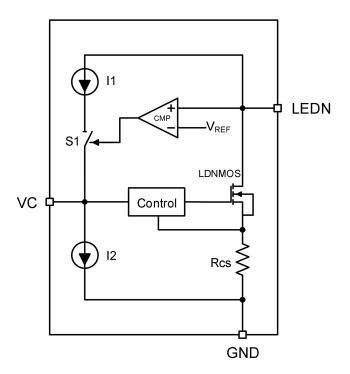


 $(V_{AC} = 120 \text{ V}, V_{LED} = 125 \text{ V}, I_{LED} = 15 \text{ mA})$

Figure 5. AC source power OFF



Block Diagram



Function Description

The DIO8242E is designed for driving one LED string and removing the 100/120 Hz LED current ripple.

Theory of operation

The LED string and DIO8242E are both supplied by an AC/DC current source. The drain of internal NMOSFET is connected to the cathode of LED string. A sensing resistor Rcs is connected between the source of NMOSFET and GND. The DIO8242E drives NMOSFET to transfer the LED current ripple to voltage ripple on NMOSFET, and ensures the constant voltage across LED string and the constant current flow through LED string. The scalable adaptive function of DIO8242E can regulate the cathode voltage of LED string to minimum to improve the efficiency of the system.

Current ripple removing

The capacitor $C_{\mathbb{C}}$ between VC and GND is an integral capacitor. DIO8242E transform the voltage on Cc to a reference voltage. The current regulator regulates LED current via negative feedback control.

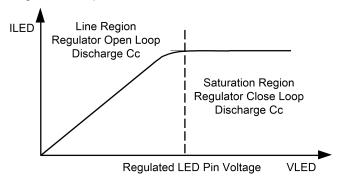
C_C should be large enough in order to remove the current ripple of the LED string. However, too large capacitor may slow down the dynamic response.

Adaptive regulation

The DIO8242E controls the voltage on C_C by monitoring the operation state of built-in N-MOSFET. The efficiency of system is relatively low when N-MOSFET always works in the saturation region. The DIO8242E detects it and charges C_C to raise the V_{VC} and I_{LED} , then the output voltage of power supply is reduced, and the voltage drop on N-MOSFET decreases.



Conversely, when N-MOSFET is working in the linear region, LED current regulation loop is open. The DIO8242E detects it and discharges C_C to reduce the V_{VC} and I_{LED} , then the output voltage of power supply is raised, and the LED current regulation loop is closed.

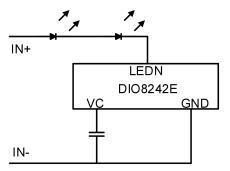


PCB design guideline

- 1. The DIO8242E should be placed far away from the power devices for better thermal performance.
- 2. The area of LED current loop should be as small as possible.

Application Information

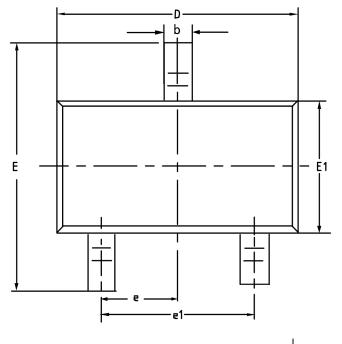
The DIO8242E design guide:

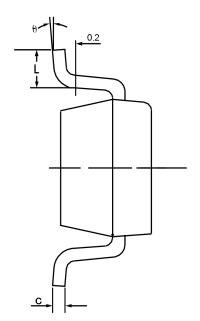


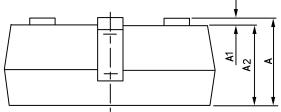
The value of the capacitor between VC and GND can determine the final amplitude of the current ripple. It should be large enough in order to remove the current ripple of the LED string. However, too large capacitor may low down the dynamic response.



Physical Dimensions: SOT23-3



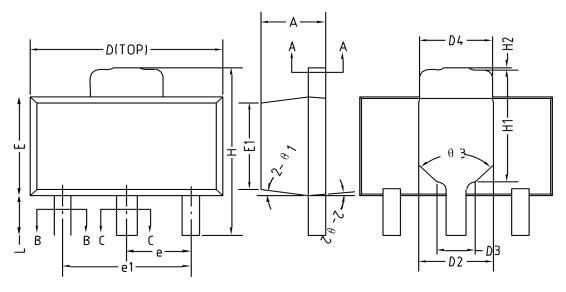


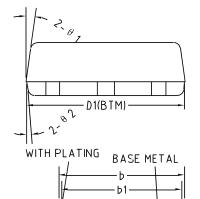


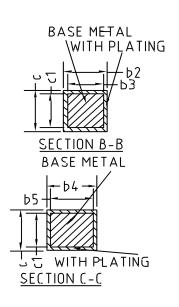
Common Dimensions (Units of measure = Millimeter)				
Symbol	Min	Max		
А	1.05	1.25		
A1	0.00	0.10		
A2	1.05	1.15		
b	0.30	0.50		
С	0.10	0.20		
D	2.82	3.02		
E1	1.50	1.70		
E	2.65	2.95		
е	0.95 BSC			
e1	1.80	2.00		
L	0.30	0.60		
Θ	0°	8°		



Physical Dimensions: SOT89-3







SECTION A-A

Common Dimensions (Units of measure = Millimeter)					
Symbol	Min	Nom	Max.		
А	1.40	1.50	1.60		
b	1.68	-	1.77		
b1	1.67	1.70	1.73		
b2	0.38	-	0.47		
b3	0.37	0.40	0.43		
b4	0.46	-	0.55		
b5	0.45	0.48	0.51		
С	0.40	-	0.44		
c1	0.39	0.40	0.41		
D	4.40	4.50	4.60		
D1	4.35	4.45	4.55		
D2	1.60	1.75	1.90		
D3	0.75	0.90	1.05		
D4	1.60	1.70	1.80		
E	2.40	2.50	2.60		
E1	2.13	-	2.19		
е	1.50BSC				
e1	3.00BSC				
Н	4.05	-	4.25		
H1	2.70	-	3.00		
H2	0	-	0.10		
L	0.89	-	1.20		
θ1	6°	8°	10°		
θ2	3°	5°	7°		
θ3	85°	90°	95°		



CONTACT US

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